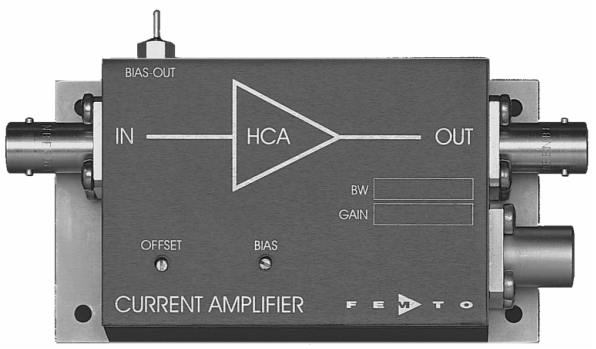
High Speed Current Amplifier



Features

- **Bandwidth and Frequency Response Independent of Detector Capacitance (up to 500 pF)**
- **Low Noise 3.5 pA/√Hz Equivalent Input Noise Current**
- **Bandwidth DC ... 4 MHz**
- **Transimpedance (Gain) 5 x 10^5 V/A**
- **Protection against ± 3.5 kV Transients**

Applications

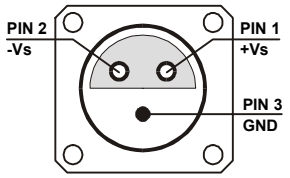
- **Photodiode and Photomultiplier Amplifier**
- **Spectroscopy**
- **Charge Amplifier**
- **Ionisation Detectors**
- **Preamplifier for Lock-Ins, A/D Converters, etc.**

Specifications

	Test Conditions	*Vs = ± 15 V, Ta = 25°C*
Gain	Transimpedance	5 x 10^5 V/A (@ 50 Ω load)
	Gain Accuracy	± 1 %
Frequency Response	Lower Cut-Off Frequency	DC
	Upper Cut-Off Frequency (- 3 dB)	4 MHz
	Rise / Fall Time (10 % - 90 %)	90 ns
	Gain Flatness	± 0.3 dB
Input	Equ. Input Noise Current	3.5 pA/√Hz (@ 100 kHz)
	Equ. Input Noise Voltage	0.8 nV/√Hz (@ 100 kHz)
	Input Bias Current	18 µA typ.
	Input Bias Current Drift	0.8 nA / K
	Offset Current Compensation	± 6 µA adjustable by offset trimpot
	Input Current Range	± 3 µA (for linear amplification)
	Input Offset Voltage	3 mV
	DC Input Impedance	50 Ω (virtual) // 5 pF
Output	Output Voltage Range	± 1.5 V (@ 50 Ω load) for linear operation and low harmonic distortion
	Output Impedance	50 Ω (terminate with 50 Ω load for best performance)
Bias Output	Bias Output Voltage Range	± 12 V, adjustable by bias trimpot
	Bias Output Impedance	10 kΩ // 1 µF

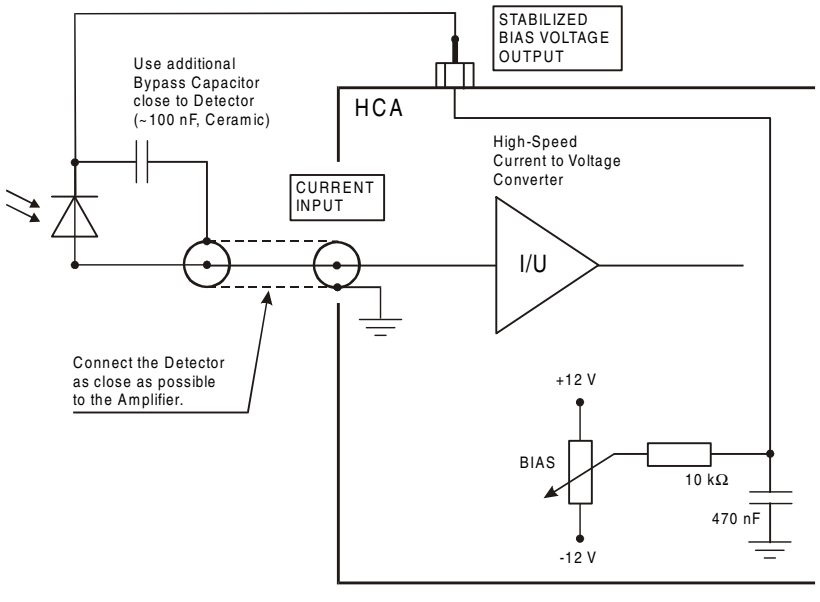
High Speed Current Amplifier

Specifications (continued)		
Power Supply	Supply Voltage	± 15 V
	Supply Current	± 50 mA typ. (depends on operating conditions, recommended power supply capability minimum ± 150 mA)
Case	Weight	210 g (0.5 lbs)
	Material	AlMg4.5Mn, nickel-plated
Temperature Range	Storage Temperature	-40 ... +100 °C
	Operating Temperature	0 ... +60 °C
Absolute Maximum Ratings	Input Voltage	± 5 V
	Input Voltage Transient	± 3.5 kV (pulsewidth 10 ns)
	Power Supply Voltage	± 22 V
Connectors	Input	BNC
	Output	BNC
	Power Supply	LEMO series 1S, 3-pin fixed socket Pin 1: + 15V Pin 2: - 15V Pin 3: GND



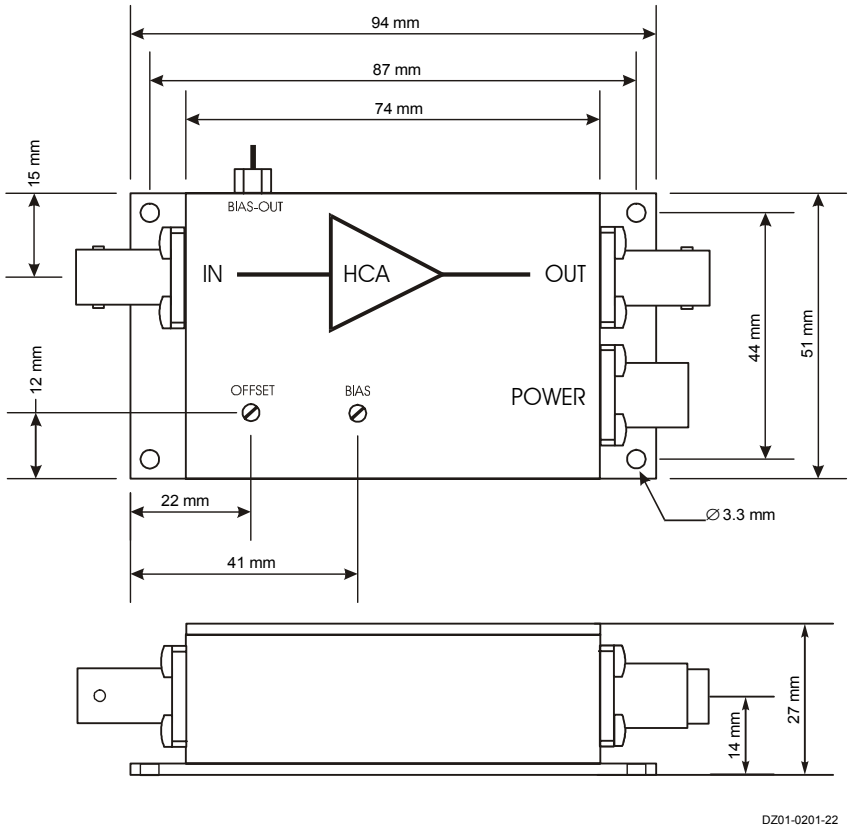
Application Diagrams

Photo Detector Biasing in Photoconductive Mode:
Best choice for high speed applications and optimum signal to noise performance.



High Speed Current Amplifier

Dimensions



FEMTO Messtechnik GmbH
Klosterstr. 64
D-10179 Berlin · Germany
Tel.: +49-(0)30-280 4711-0
Fax: +49-(0)30-280 4711-11
e-mail: info@femto.de
http://www.femto.de